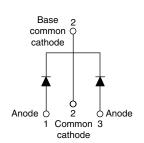


Vishay Semiconductors

Schottky Rectifier, 2 x 15 A

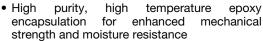




PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 15 A				
V_R	45 V				
V _F at I _F	See Electrical table				
I _{RM} max.	100 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Common cathode				
E _{AS}	10 mJ				

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	SYMBOL CHARACTERISTICS VALUES UNITS						
I _{F(AV)}	Rectangular waveform (per device)	30	Α				
V _{RRM}		35/45	V				
I _{FRM}	T _C = 123 °C (per leg)	30	۸				
I _{FSM}	t _p = 5 μs sine	1020	- A				
V _F	20 A _{pk} , T _J = 125 °C	0.6	V				
T _J	Range	- 65 to 150	°C				

VOLTAGE RATINGS					
PARAMETER SYMBOL VS-MBR3045CTPbF VS-MBR3045CT-N3 UNITS					
Maximum DC reverse voltage	V_{R}	45	45	V	
Maximum working peak reverse voltage	V_{RWM}	40	40	V	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CON	NDITIONS	VALUES	UNITS	
Maximum average per leg		T 123 °C rated V-	$T_C = 123 ^{\circ}\text{C}$, rated V_R			
forward current per device	I _{F(AV)}	TC = 123 C, rated V _R				
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20	Rated V _R , square wave, 20 kHz, T _C = 123 °C			
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1020	А	
	1 0.00	Surge applied at rated load conditions halfwave, single phase, 60 Hz		200		
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 5 \text{mH}$		10	mJ	
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5$ x V_R typical		2	Α	



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS		
		30 A	T _J = 25 °C	0.76		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	T _J = 125 °C	0.6	V	
		30 A	1J = 125 O	0.72		
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Dated DC valtage	1	- mA	
		T _J = 125 °C	Rated DC voltage	100		
Threshold voltage	V _{F(TO)}	T - T movimum		0.29	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		13.6	m $Ω$	
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		800	pF	
Typical series inductance	L _S	Measured from top of termin	8.0	nΗ		
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/µs			V/µs	

Note

 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	T_J		- 65 to 150	°C		
Maximum storage temperature range	T _{Stg}		- 65 to 175	C		
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.5			
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased Only for TO-220	0.50	°C/W		
Maximum thermal resistance, junction to ambient	R _{thJA}	R _{thJA} DC operation For D ² PAK and TO-262				
Approximate weight			2	g		
Approximate weight			0.07	OZ.		
Mounting torque minimum		Non-link-destand thousands		kgf ⋅ cm		
Mounting torque maximum		Non-lubricated threads	12 (10)	$(lbf \cdot in)$		
Marking device		Case style TO-220AB	MBR3045CT			

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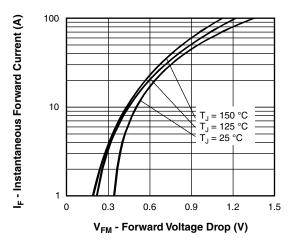


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

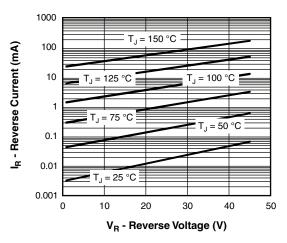


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

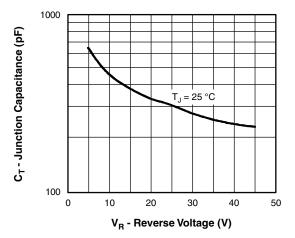


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

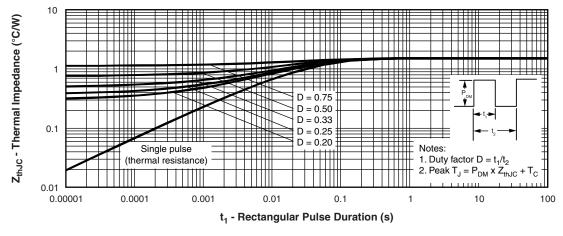


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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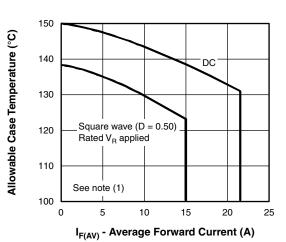


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

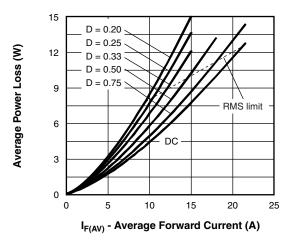


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

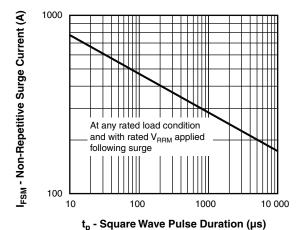


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

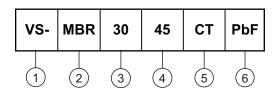
Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Schottky MBR series

3 - Current rating (30 = 30 A)

- Voltage ratings (045 = 45 V)

- CT = Essential part number

6 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-MBR3045CTPbF	50	1000	Antistatic plastic tube			
VS-MBR3045CT-N3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Doub wooding information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	
		•	•	•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



Legal Disclaimer Notice

Vishay

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